



# Description

The DFB-XXX-BF-XX-CW-Fx-Hx-N347 series of Multi-Quantum Well (MQW) Distributed Feedback (DFB) lasers have been designed specifically to satisfy the requirements of the high power, narrow linewidth application.

The devices feature high output power and wide operating temperature range.

Their 14-pin butterfly packages are either pincompatible with standard SONET OC-48 devices or can be "floating" from the metal house.

# **Features**

- Advanced Multiple Quantum Well (MQW) Distributed Feedback (DFB) Laser Design
- High-output power
- Industry-standard 14-pin Butterfly package
- Option of SMF-28 Fiber Pigtail or PM fiber

# Applications

- □ CATV external modulation
- DWDM
- □ Intermediate and long-distance fiberoptic transmitter





## **Absolute Maximum Ratings**

Parameter	Symbol	Symbol Condition		Max	Unit
Operating Case Temperature	Tc	I=I <sub>op</sub>	-20	65	°C
Storage Temperature	T <sub>stg</sub>		-40	85	°C
Laser Forward Current	$I_{f}$			450	mA
Laser Reverse Bias	Vr			2	V
Photodiode Reverse Bias	V <sub>rpd</sub>			10	V
TEC Current	$\mathbf{I}_{TEC}$	-20 °C < $T_c$ < 65 °C, $T_{op}$ =25 °C, $I_f$ = $I_{op}$		1.5	А

# **Electrical and Optical Characteristics** Parameters are tested at 25 °C unless otherwise noted.

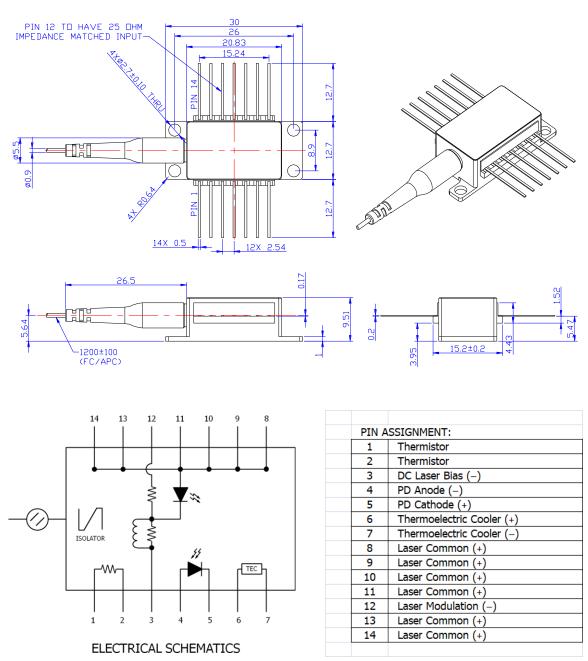
Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions
Operating Case	т Т	-20		65	°C	
Temperature	Tc	-20		65	٠ر	
Laser Set temperature	TL	15		35	°C	
Optical Output Power	Po	25		40	mW	CW
Threshold Current	$\mathrm{I}_{\mathrm{th}}$			30	mA	T <sub>L</sub> =25°C
Forward Voltage	V <sub>F</sub>			2.5	V	P <sub>o</sub> =P <sub>L</sub>
Operating Current	I <sub>op</sub>			450	mA	$P_0=P_L$ , $T_L=25^{\circ}C$
Center Wavelength*	$\lambda_{c}$	Refe	r to order o	ption	nm	$P_0=P_L$ , CW, 15 °C $\leq T_L \leq 35$ °C
Center WL Tolerance	Δλc	-0.1		0.1	nm	$P_0=P_L$ , CW, 15 °C $\leq T_L \leq 35$ °C
Spectral Linewidth	Δλ			2	MHz	$P_0=P_L$ , $T_L=25^{\circ}C$
Polarization Extinction	PER	18	20		dB	Only with PANDA PM fiber
Ratio						option, slow axis align with E-
						Field
Optical Isolation	ISO	32			dB	
Side-mode Suppression	SMSR	30			dB	$P_0 = P_1$
Ratio		50			-	· -
Relative Intensity Noise	RIN			-160	dB/Hz	CW, T <sub>L</sub> =25 °C
Monitor Current	I <sub>mon</sub>	10		150	μA/mW	V <sub>rpd</sub> =5 V
Monitor Dark Current	ID			200	nA	V <sub>rpd</sub> =5 V
Tracking Error	γ	-0.5		0.5	dB	$I_{mon}$ =const, $\gamma$ =10 log (P <sub>o</sub> /P <sub>L</sub> )
						[dB]
Thermistor Resistance	Rt	9.5		10.5	kΩ	T=25°C
Thermistor B Constant	В		3900		K	T=25°C
TEC Current	I <sub>C</sub>			1.5	Α	ΔT=40°C
TEC Voltage	Vc			2.5	V	ΔT=40°C

\* See Ordering Options and contact AOI marketing for availability.



# **Outline Diagram**

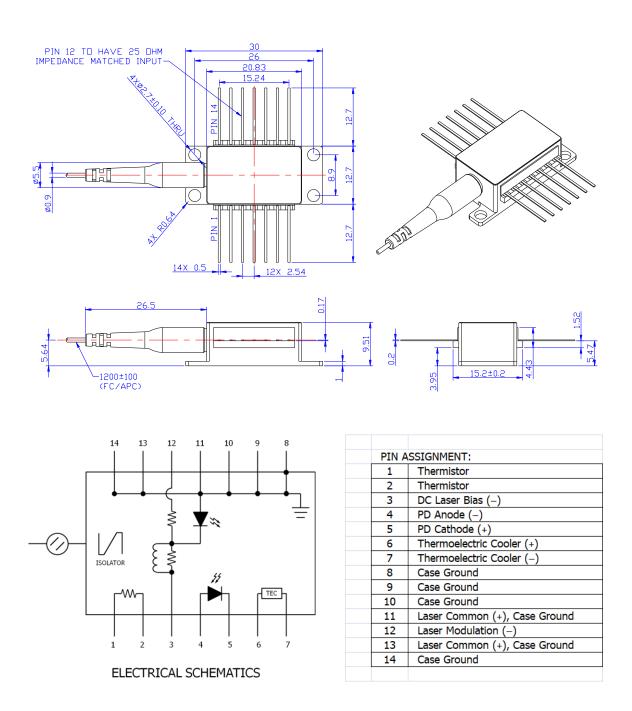
Dimensions are in millimeters



## H1 (Floating LD Anode design)

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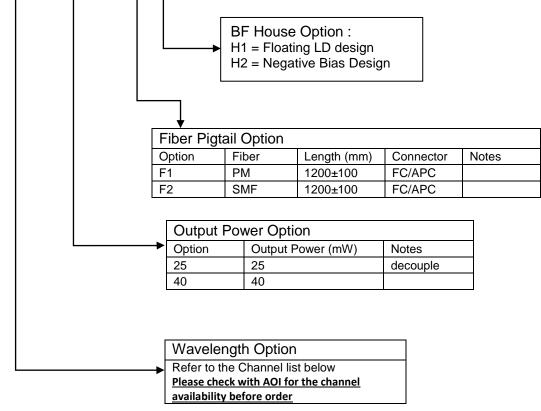


## H2 (Negative Bias Design, Case GRD connected to LD Anode)



## **Ordering Options**





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#### ITU-T DWDM Channel

ITU Channel	Frequency (THz)	Wavelength (nm)	ITU Channel	Frequency (THz)	Wavelength (nm)
920	192.0	1561.42	942	194.2	1543.73
921	192.1	1560.61	943	194.3	1542.94
922	192.2	1559.79	944	194.4	1542.14
923	192.3	1558.98	945	194.5	1541.35
924	192.4	1558.17	946	194.6	1540.56
925	192.5	1557.36	947	194.7	1539.77
926	192.6	1556.55	948	194.8	1538.98
927	192.7	1555.75	949	194.9	1538.19
928	192.8	1554.94	950	195.0	1537.4
929	192.9	1554.13	951	195.1	1536.61
930	193.0	1553.33	952	195.2	1535.82
931	193.1	1552.52	953	195.3	1535.04
932	193.2	1551.72	954	195.4	1534.25
933	193.3	1550.92	955	195.5	1533.47
934	193.4	1550.12	956	195.6	1532.68
935	193.5	1549.32	957	195.7	1531.9
936	193.6	1548.51	958	195.8	1531.12
937	193.7	1547.72	959	195.9	1530.33
938	193.8	1546.92	960	196.0	1529.55
939	193.9	1546.12	961	196.1	1528.77
940	194.0	1545.32	962	196.2	1527.99
941	194.1	1544.53			

Please consult factory for wavelength availability before ordering.

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#### **Safety Information**

All versions of this laser are Class 1M laser products per IEC<sup>1</sup>/EN<sup>2</sup> 60825-1:2001-08. Users should observe safety precautions such as those recommended by ANSI<sup>3</sup> Z136.1-2000, ANSI Z36.2-1997 and IEC 60825-1:2001-08.

#### Notes about Laser Safety Class:

The Food and Drug Administration's Center for Devices and Radiological Health (FDA/CDRH) in the USA has decided to harmonize their requirements with 21 CFR 1040.10 and 1040.11 with the IEC/EN 60825-1 and IEC/EN 60601-2-22 standards. This process has not yet happened and in the interim, the CDRH agency has released <u>Laser Notice No.50</u> to reduce the regulatory burden. This notice allows IEC/EN classification and labeling of lasers within the USA.

#### IEC<sup>1</sup>/EN<sup>2</sup> 60825-1 Laser Class

**Class 1M**: laser is safe for all conditions of use except when passed through magnifying optics such as microscopes and telescopes. Class 1M lasers produce large-diameter beams, or beams that are divergent. The MPE for a Class 1M laser cannot normally be exceeded unless focusing or imaging optics are used to narrow the beam. If the beam is refocused, the hazard of Class 1M lasers may be increased and the product class may be changed. A laser can be classified as Class 1M if the total output power is below (IEC/EN) class 3B but the power that can pass through the pupil of the eye is within Class 1.

#### FDA Laser Class

**Class IIIB**: moderate power lasers (cw: 5-500 mW, pulsed: 10 J/cm<sup>2</sup> or the diffuse reflection limit, whichever is lower). In general Class IIIB lasers will not be a fire hazard, nor are they generally capable of producing a hazardous diffuse reflection. Specific controls are recommended.

This product does not conform to 21 CFR 1040.10 and 1040.11. Consequently, this laser module is only intended for use as a component by manufacturers of electronic products and equipment.

Wavelength =1270 - 1610 nm Maximum Power = 75mW Single-mode fiber pigtail Fiber Numerical Aperture = 0.14

Labeling is not affixed to the laser module due to size constraints; rather, labeling is placed on the outside of the shipping box.

This product is not shipped with a power supply.

Caution: use of controls or adjustments or performance of procedures other than those specified herein may result in hazardous radiation exposure.



classified in accordance with IEC 60825-1: 2001-08

(1) IEC is a registered trademark of the International Electrotechnical Commission

(2) Within Europe the IEC standard has been adopted as a European Normative standard known as EN 60825, and each European country will have its own version of this standard, for example, the British Standards version known as BS EN 60825. There can be small differences between the different countries versions of EN 60825, and these are in part caused by the process of translating the standard into the native language of that country.

(3) ANSI is a registered trademark of the American National Standards Institute.